







## ILS LITH ITY PATENT APPLICATION

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SCANNED QA	PATENT DATE

	0017/00100	CLASS	SUBCLASS	ART UNIT	EXAMINER (
APPLICATION NO.	CONT/PRIOR	257	30505400	2811	PTAL
09/008525	<b>'</b>				

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SEMICONDUCTOR MEMORY DEVICE AND METHOL OF MANUFACTURING FOR PREVENTING BIT LINE OXIDATION

PTO-2040 12/99

## PREPARED AND APPROVED FOR ISSUE

ISSUING CLASSIFICATION						
ORIG	RIGINAL CROSS REFERENCE(S)					
CLASS	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)			
INTERNATIONAL	CLASSIFICATION					
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	/		Continued on Issue Slip Inside File Jacket			

TERMINAL	DRAWINGS			CLAIMS ALLOWED	
DISCLAIMER	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
				NOTICE OF ALL	OWANCE MAILED
a) The term of this patent subsequent to (date) has been disclaimed.	(Assistant	Examiner)	(Date)		
b) The term of this patent shall					
not extend beyond the expiration date of U.S Patent. No.				ISSUE FEE	
			(200)	Amount Due	Date Paid
	(Primary Examiner) (Date)			ISSUE BA	TCH NUMBER
c) The terminalmonths of this patent have been disclaimed.	(Legal Instrum	nents Examiner)	(Date)		

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